

# Mu2e SiPMs test

Muse outreach program for university student

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# Measurement description

Each group will measure the SiPM I-V curve for :

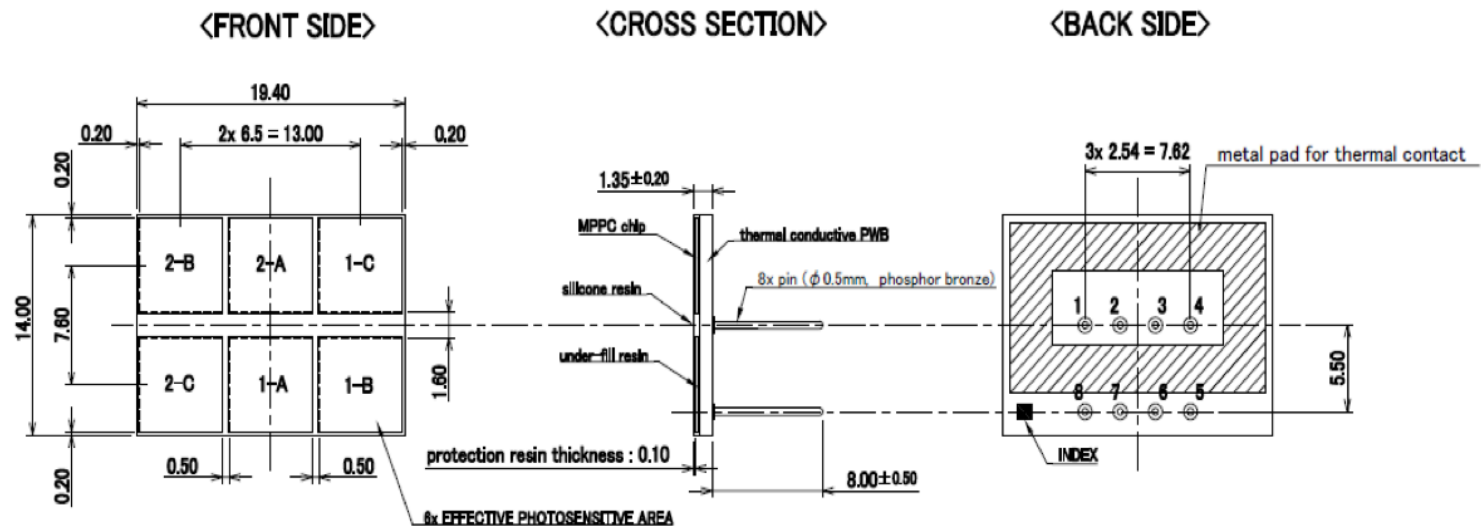
- 1 not irradiated SiPM
- 1 irradiated SiPM at different temperatures (20 – 15 – 10 - 5 °C)

# Mu2e SiPM (1)

- Mu2e SiPMs are made of a 2x3 matrix (6 cells) of 6x6 mm<sup>2</sup>
  - Parallel arrangement of two groups of three cells biased in series
  - 2 SiPM per crystals to ensure redundancy
  - Fast signal for pileup and timing resolution
- Operational voltage of a single 6x6 mm<sup>2</sup> cell:  $V_{op} = V_{br} + 3V$



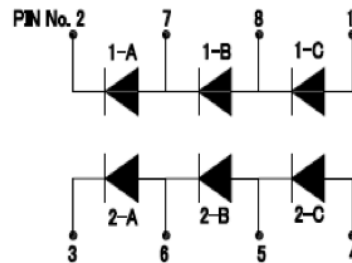
# Mu2e SiPM (2)



EFFECTIVE PHOTOSENSITIVE AREA : 6.0mm x 6.0mm  
MPPC CHIP SIZE : 6.1mm x 6.1mm

\* 1-A ~ 2-C : CHANNEL No.

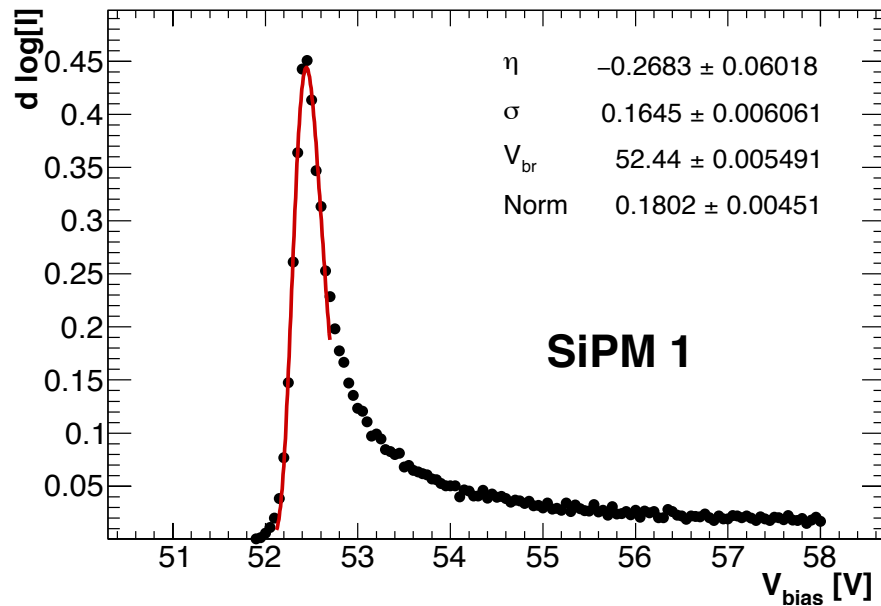
GENERAL TOLERANCE : ±0.1



PIN No.	1	2	3	4
Channel	Anode (1-C)	Cathode (1-A)	Cathode (2-A)	Anode (2-C)

PIN No.	8	7	6	5
Channel	Anode (1-B)	Anode (1-A)	Anode (2-A)	Anode (2-B)
	Cathode (1-C)	Cathode (1-B)	Cathode (2-B)	Cathode (2-C)
	[short]	[short]	[short]	[short]

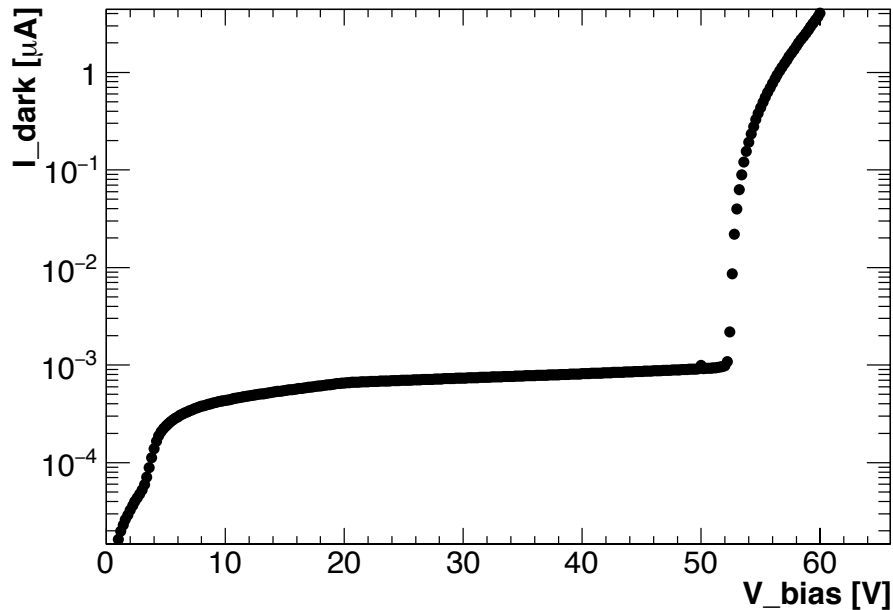
# I-V curve and $V_{br}$



- $V \ll V_{br}$ : I monotonically increase with V
- $V \sim V_{br}$ : I increases more rapidly with each voltage step, reaching the highest rate of increase when  $V = V_{br}$
- $V > V_{br}$ : Geiger mode, gain is linearly proportional to  $\Delta V$

If  $V > V_{br}$  I increases faster the linear. Total increase rate of I is between  $V^n$  and  $e^V$ . Calculating derivative of I curve in log scale **the local maximum value is  $V_{br}$**

# I-V curve and $V_{br}$

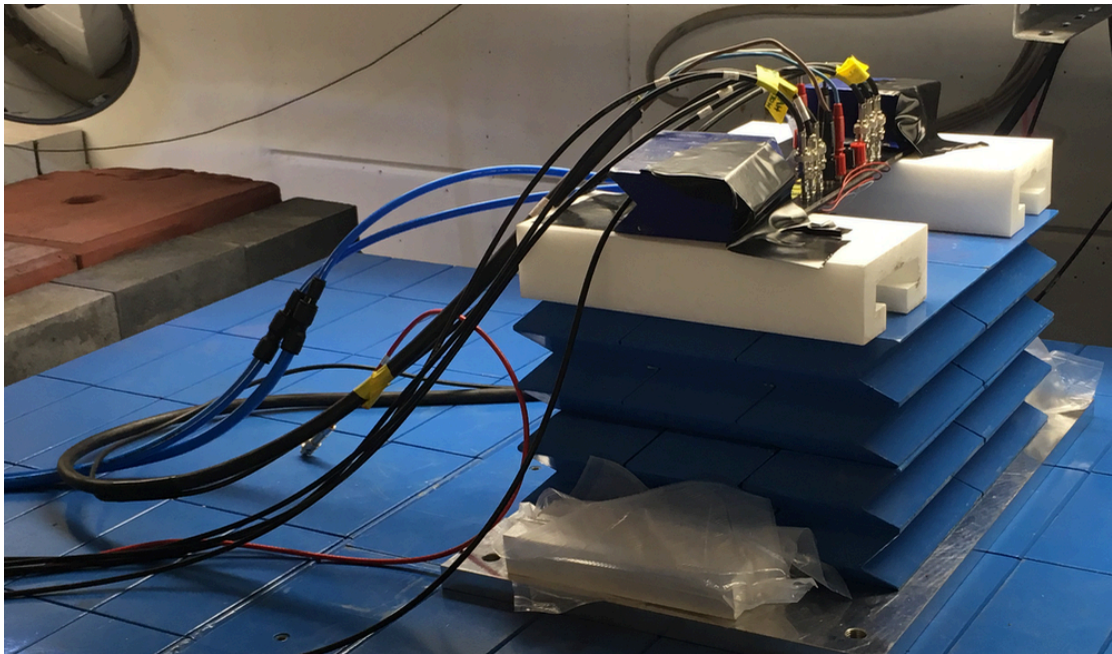


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# Irradiation measurement

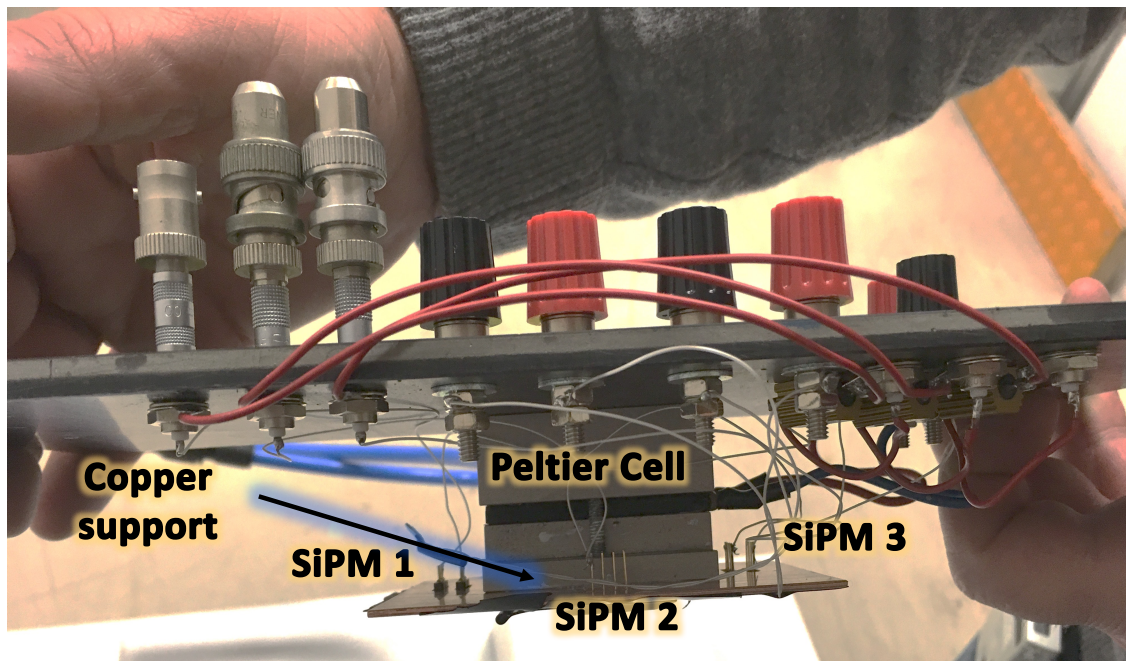
- Each SiPMs have been tested @ HZDR (Dresden, Germany)
- Total flux ( $8 \times 10^{11} \text{ n}_{1\text{MeV}}/\text{cm}^2$ )



- **3 Sipm tested at the same time**
- **Single cell** current acquired with a Keythley
- Chiller+ Peltier cell
- $T_{\text{back}}$  monitored with a PT 100

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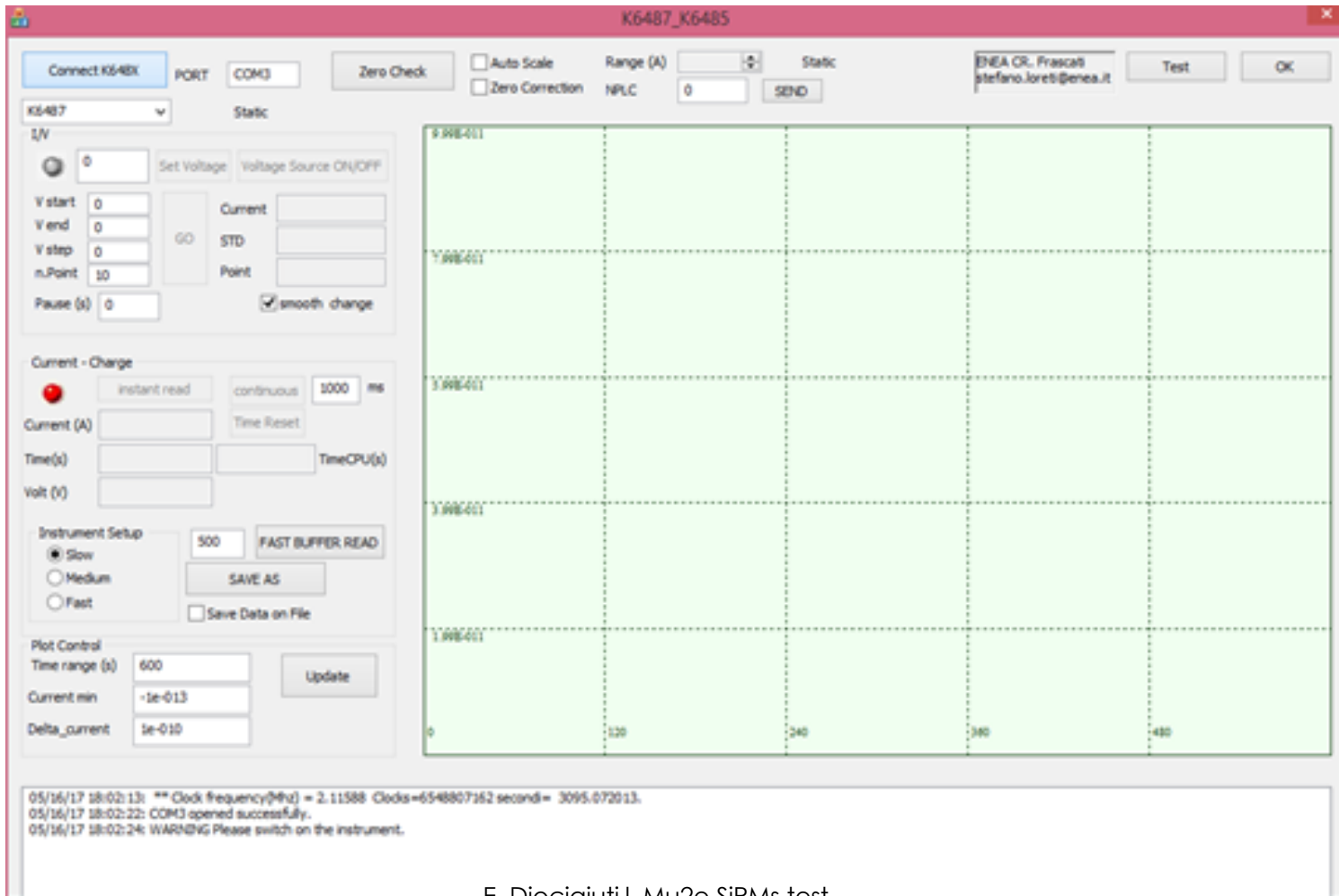
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# Program you will use..



# Ready to start?

- Open the program K648x
- Select COM3 and the Keithley 6487
- Zerocheck and autoscale
- Select the directory to save the data on ( MUSE\_outreach)
- Select the  $V_{\text{bias}}$  range and V step

**GO!**